

## PATENT ABSTRACTS OF JAPAN

(11)Publication number : 2001-143771

(43)Date of publication of application : 25.05.2001

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(51)Int.Cl.

H01M 14/00

H01L 31/04

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(21)Application number : 11-322911

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(22)Date of filing :

12.11.1999

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### (54) PHOTOELECTRIC TRANSDUCER AND PHOTOELECTRIC CELL

(57)Abstract:

**PROBLEM TO BE SOLVED:** To provide a photoelectric transducer and a photoelectric cell using the same, which has excellent energy conversion efficiency and is especially excellent in durability and energy conversion efficiency.

**SOLUTION:** The photoelectric transducer includes a conductive support, a semiconductor fine particle layer sensitized with a pigment placed on the conductive support, and a charge transfer layer. An additional semiconductor layer is disposed between the semiconductor fine particle layer and the conductive support. Also, a molten salt electrolyte or an inorganic hole transfer material is used in the charge transfer layer.

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### LEGAL STATUS

[Date of request for examination]

[Date of sending the examiner's decision of rejection]

[Kind of final disposal of application other than the examiner's decision of rejection or application converted registration]

[Date of final disposal for application]

[Patent number]

[Date of registration]

[Number of appeal against examiner's decision of rejection]

[Date of requesting appeal against examiner's decision of rejection]

[Date of extinction of right]